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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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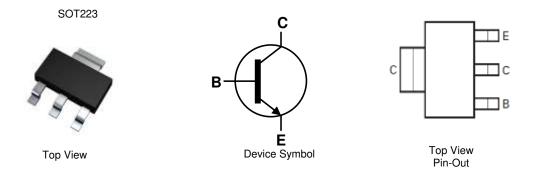
100V NPN MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > 100V
- I_C = 6A High Continuous Collector Current
- I_{CM} = 10A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < 150mV @ 2A
- $R_{CE(SAT)} = 50 m\Omega$ for a Low Equivalent On-Resistance
- h_{FE} Specified up to 10A for a High Gain Hold-Up
- Complementary PNP Type: FZT953
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (Approximate)



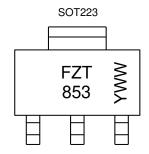
Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT853TA	AEC-Q101	FZT853	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



FZT 853 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5 = 2015) WW or $\overline{W}W$ = Week Code (01–53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	200	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	6	Α
Peak Pulse Current	I _{CM}	10	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		3.0 24	W	
Linear Derating Factor	(Note 6)	P _D	1.6 12.8	mW/°C	
Thermal Decistores Junction to Ambient	(Note 5)	$R_{\theta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	78	°C/W	
Thermal Resistance Junction to Lead (Note 7)		R _{eJL}	8.8		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

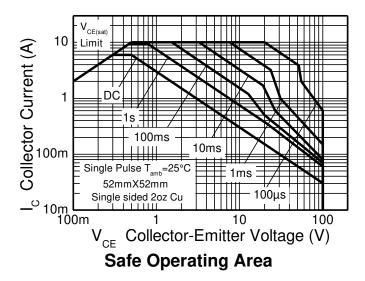
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

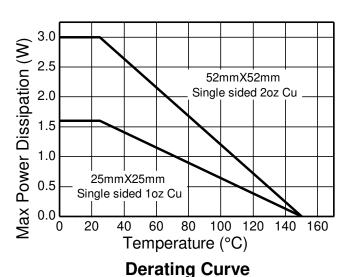
Notes:

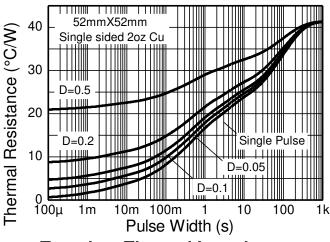
- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 6. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

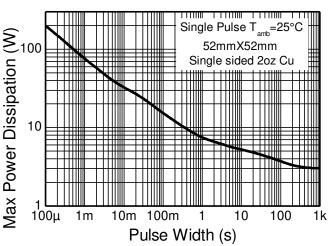


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation



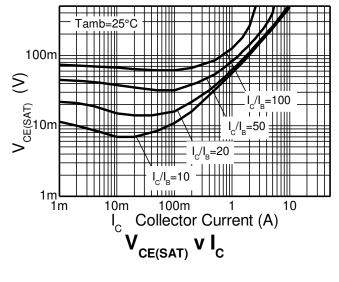
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

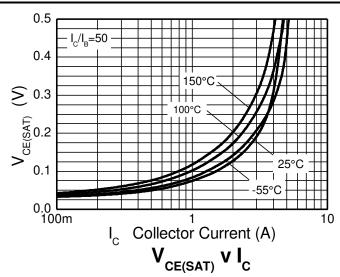
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	200	300	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage	BV _{CER}	200	300	_	V	$I_C = 1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	100	120	_	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	_	V	$I_E = 100\mu A$
Collector Cut-Off Current	I _{CBO}	_	<1	10	nA	V _{CB} = 150V
Concotor out on current	ICBO		_	1	μΑ	$V_{CB} = 150V, T_A = +100^{\circ}C$
Collector Cut-Off Current	I _{CER}	_	<1	10	nA	$V_{CE} = 150V, R_B \le 1k\Omega$
Concetor Gut Cir Guirent	ICER		_	1	μΑ	$V_{CE} = 150V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I _{EBO}	_	<1	10	nA	$V_{EB} = 6V$
	h _{FE} -	100	200	_	l	$I_C = 10$ mA, $V_{CE} = 2$ V
DC Current Gain (Note 9)		100	200	300		$I_C = 2A$, $V_{CE} = 2V$
DC Current Gain (Note 9)		50	100	_		$I_C = 4A$, $V_{CE} = 2V$
		20	30	_		$I_C = 10A, V_{CE} = 2V$
		_	14	50		$I_C = 100 \text{mA}, I_B = 5 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(SAT)}$	_	100	150	mV	$I_C = 2A$, $I_B = 100mA$
	, ,	_	250	340		$I_C = 5A$, $I_B = 500mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(SAT)}$	_	1,050	1,250	mV	$I_C = 5A$, $I_B = 500mA$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(ON)}	_	900	1,100	mV	$I_C = 5A$, $V_{CE} = 2V$
Current Gain-Bandwidth Product (Note 9)	f _T	_	130	_	MHz	$I_{C} = 100 \text{mA}, V_{CE} = 10 \text{V},$ f = 50 MHz
Output Capacitance	Сово	_	35	_	pF	$V_{CB} = 10V$, $f = 1MHz$
Switching Times	ton	_	50	_	ns	$I_{C} = 1A, V_{CC} = 10V,$
Owitering Times	toff	_	1,650	_	115	$I_{B1} = -I_{B2} = 100 \text{mA}$

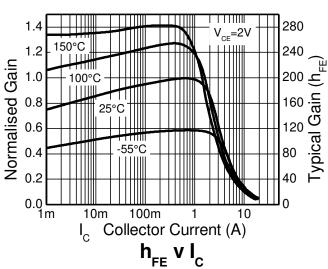
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

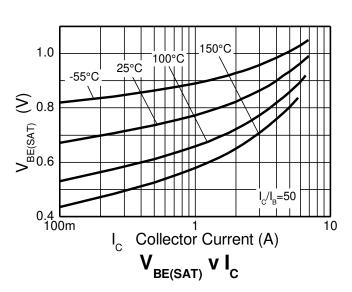


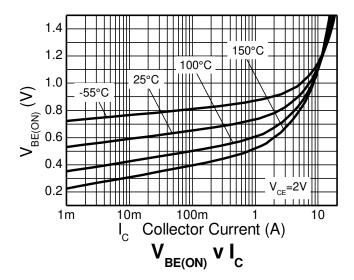
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







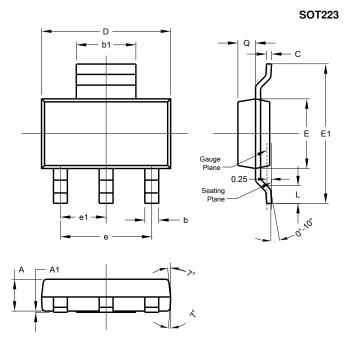






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

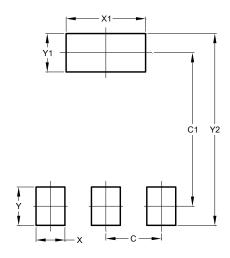


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A 1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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